NSN 5961-00-619-7193

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No



View Online at https://aerobasegroup.com/nsn/5961-00-619-7193

Metal	
Overall Length:	
Between 0.170 inches a	nd 0.210 inches
Terminal Length:	
0.500 inches	
Overall Diameter:	
Between 0.209 inches a	nd 0.230 inches
Internal Configuration	
Field effect	
Electrode Internally-el	ectrically Connected To Case:
Base	
Mounting Method:	
Terminal	
Terminal Circle Diame	ter:
0.100 inches	
Features Provided:	
Hermetically sealed cas	e
Semiconductor Materi	al:
Silicon	
Voltage Rating In Volt	S Per Characteristic:
25.0 drain to source vo	tage and 35.0 drain to gate voltage and 25.0 gate to source voltage
Current Rating Per Ch	aracteristic:
30.00 milliamperes drai	n current
Power Rating Per Cha	racteristic:
300.0 milliwatts total po	wer dissipation
Maximum Operating T	empurature Per Measurement Point:
175.0 degrees celsius ju	Inction
Precious Material And	Location:
Terminal surfaces gold	
Precious Material:	
Gold	
Test Data Document:	
95542-958-052 drawing	(this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specificati	on, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Qu	antity:
4 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	

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